NSN 5961-01-099-8429

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-099-8429 **Inclosure Material:** Metal **Overall Length:** 39.22 millimeters **Overall Height:** 8.38 millimeters **Overall Width:** 25.80 millimeters **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204ae **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage **Current Rating Per Characteristic:** 30.00 amperes drain current **Power Rating Per Characteristic:** 180.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**